Vishay Semiconductors

High Performance Schottky Rectifier, 1.5 A



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DO-214AC (SMA)

| PRODUCT SUMMARY | | | | | |
|----------------------------------|-----------------|--|--|--|--|
| Package | DO-214AC (SMA) | | | | |
| I _{F(AV)} | 1.5 A | | | | |
| V _R | 40 V | | | | |
| V _F at I _F | 0.34 V | | | | |
| I _{RM} | 20 mA at 125 °C | | | | |
| T _J max. | 150 °C | | | | |
| Diode variation | Single die | | | | |
| E _{AS} | 6.0 mJ | | | | |

FEATURES

- Extremely low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Surface mountable
- Compact size
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Switching power supplies
- Meter protection
- · Reverse protection for power input to PC board circuits
- · Battery isolation and charging
- · Low threshold voltage diode
- Freewheeling or by-pass diode
- Low voltage clamp

DESCRIPTION

The VS-15MQ040-M3 Schottky rectifier is designed to be used for low power applications where a reverse voltage of 40 V is encountered and surface mountable is required.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | |
|-----------------------------------|---|-------------|-------|--|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | | |
| I _{F(AV)} | Rectangular waveform | 1.5 | A | | | | |
| V _{RRM} | | 40 | V | | | | |
| I _{FSM} | t _p = 5 μs sine | 330 | A | | | | |
| V _F | 2 A _{pk} , T _J = 125 °C | 0.43 | V | | | | |
| TJ | Range | -40 to +150 | ٦° | | | | |

| VOLTAGE RATINGS | | | | | | |
|--------------------------------------|------------------|---------------|-------|--|--|--|
| PARAMETER | SYMBOL | VS-15MQ040-M3 | UNITS | | | |
| Maximum DC reverse voltage | V _R | 40 | V | | | |
| Maximum working peak reverse voltage | V _{RWM} | 40 | v | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--|------------------|---|---|--------|-------|--|
| PARAMETER | SYMBOL | TEST CONDIT | IONS | VALUES | UNITS | |
| Maximum average forward current | 1 | 50 % duty cycle at T_L = 105 °C, n On PC board 9 mm ² island (0.013 mm thick copper pad area | Ū | 2.1 | A | |
| See fig. 4 | | 50 % duty cycle at T_L = 113 °C, n On PC board 9 mm ² island (0.013 mm thick copper pad area | 1.5 | A | | |
| Maximum peak one cycle | | 5 µs sine or 3 µs rect. pulse | Following any rated | 330 | | |
| non-repetitive surge current See fig. 6 | I _{FSM} | 10 ms sine or 6 ms rect. pulse | load condition and with rated V _{RRM} applied | 140 | A | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 1 A, L = 12 mH | | 6.0 | mJ | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical | | 1.0 | А | |

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HALOGEN



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| ELECTR | | SPECIE | ICATION | S |
|--------|-------|--------|---------|---|
| ELEVIN | ICAL. | SPECIF | ICATION | 3 |

| PARAMETER | SYMBOL | TES | TEST CONDITIONS | | |
|---------------------------------|--------------------------------|---|---------------------------------------|------|------|
| | | 1.5 A | T 05 %C | 0.43 | |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 2 A | T _J = 25 °C | 0.49 | V |
| See fig. 1 | VFM (1) | 1.5 A | T 105 %C | 0.34 | |
| | | 2 A | T _J = 125 °C | 0.43 | |
| Maximum reverse leakage current | 1 | T _J = 25 °C | V - Reted V | 0.5 | mA |
| See fig. 2 | I _{RM} | T _J = 125 °C | V _R = Rated V _R | 20 | |
| Threshold voltage | V _{F(TO)} | | | 0.26 | V |
| Forward slope resistance | r _t | $I_{J} = I_{J}$ maximum | $T_J = T_J$ maximum | | mΩ |
| Typical junction capacitance | CT | $V_R = 10 V_{DC}$, $T_J = 25 \text{ °C}$, test signal = 1 MHz | | 134 | pF |
| Typical series inductance | L _S | Measured lead to lead 5 mm from package body | | 2.0 | nH |
| Maximum voltage rate of change | dV/dt | Rated V _R 10 000 V/µ | | | V/µs |

Note

 $^{(1)}\,$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|------------------------------------|-------------------------------|-------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum junction and storage temperature range | T_{J} ⁽¹⁾ , T_{Stg} | | -40 to +150 | °C | | |
| Maximum thermal resistance, junction to ambient | R _{thJA} | DC operation | 80 | °C/W | | |
| Approximate weight | | | 0.07 | g | | |
| Approximate weight | | | 0.002 | oz. | | |
| Marking device | | Case style SMA (similar D-64) | Х | F | | |

Note

(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



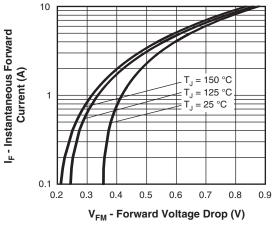
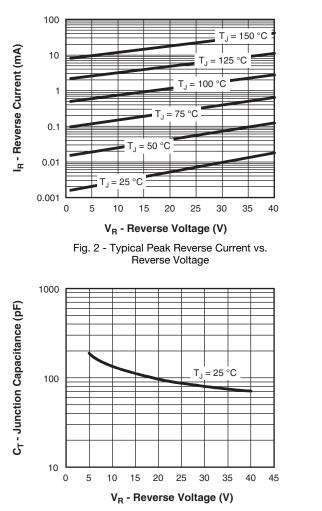
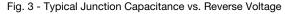
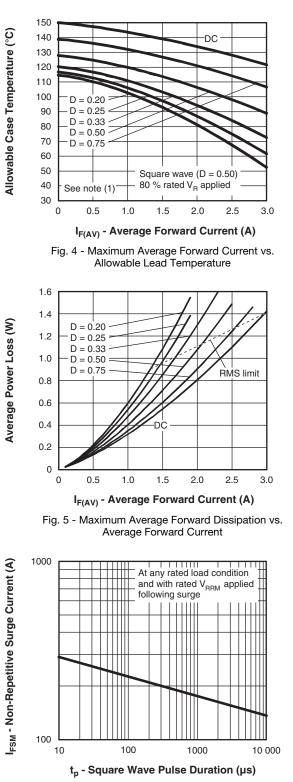


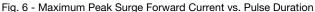
Fig. 1 - Maximum Forward Voltage Drop Characteristics





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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

Revision: 20-Jan-15

3

Document Number: 93366

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ORDERING INFORMATION TABLE

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VISHA

| Device code | VS- | 15 | м | Q | 040 | -M3 | |
|-------------|-----|-------|-----------------------------|------------|-----------|---------|--|
| | | 2 | 3 | 4 | 5 | 6 | |
| | 1 | - Vis | hay Sen | niconduo | ctors pro | oduct | |
| | 드 | - Cur | rent rati | ng | | | |
| | 3 | - M= | M = SMA | | | | |
| | | | Q = Schottky "Q" series | | | | |
| | Ë | | Voltage rating (040 = 40 V) | | | | |
| | 6 | - Env | vironmer | ntal digit | : | | |
| | | -M3 | s = halog | gen-free | , RoHS- | complia | |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|------------------------|------------------------|------------------------------------|--|--|--|
| PREFERRED P/N | PREFERRED PACKAGE CODE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | |
| VS-15MQ040-M3/5AT | 5AT | 7500 | 13" diameter plastic tape and reel | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|-------------------------------------|--------------------------|--|--|--|--|
| Dimensions www.vishay.com/doc?95400 | | | | | |
| Part marking information | www.vishay.com/doc?95403 | | | | |
| Packaging information | www.vishay.com/doc?95404 | | | | |



Outline Dimensions

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SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)





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